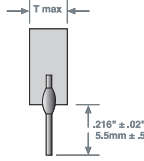
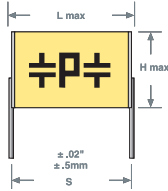
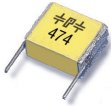


Capacitor Type

RA



- Efficient size
- Rugged construction
- Does not fail short – Self healing
- Low ESR/ESL
- No entrapped moisture or air in self-encased design
- No dissimilar metals to chemically degrade or attract moisture
- High dv/dt
- Wave solderable
- Operating temperature range: -55°C to +125°C
- Made in U.S.A.

100 VDC / 80 VAC

PF Code	Value μF	L Max	TMax	H Max	S \pm .02 [.5]	d	Max dv/dt (V/ μs)	Case	Part No.
224	0.22	0.350 (8.9)	0.155 (3.9)	0.280 (7.1)	0.295 (7.5)	0.025 (.6)	75	RA3	224K100RA3 __
474	0.47	0.350 (8.9)	0.180 (4.6)	0.305 (7.7)	0.295 (7.5)	0.025 (.6)	65	RA3	474K100RA3 __
105	1.0	0.450 (11.4)	0.175 (4.4)	0.285 (7.2)	0.394 (10)	0.025 (.6)	35	RA4	105K100RA4 __
225	2.2	0.350 (8.9)	0.250 (6.3)	0.350 (8.9)	0.295 (7.5)	0.025 (.6)	25	RA3	225K100RA3 __
225	2.2	0.450 (11.4)	0.205 (5.2)	0.285 (7.2)	0.394 (10)	0.025 (.6)	25	RA4	225K100RA4 __
335	3.3	0.450 (11.4)	0.250 (6.3)	0.350 (8.9)	0.394 (10)	0.025 (.6)	25	RA4	335K100RA4 __
405	4.0	0.450 (11.4)	0.200 (5.1)	0.380 (9.7)	0.394 (10)	0.032 (.8)	20	RA4	405K100RA4 __
505	5.0	0.450 (11.4)	0.220 (5.6)	0.480 (12.2)	0.394 (10)	0.032 (.8)	20	RA4	505K100RA4 __
106	10.0	0.650 (16.5)	0.260 (6.6)	0.460 (11.7)	0.591 (15)	0.032 (.8)	13	RA6	106K100RA6 __

250 VDC / 160 VAC

PF Code	Value μF	L Max	TMax	H Max	S \pm .02 [.5]	d	Max dv/dt (V/ μs)	Case	Part No.
104	0.1	0.450 (11.4)	0.160 (4.1)	0.255 (6.5)	0.394 (10)	0.025 (.6)	100	RA4	104K250RA4 __
224	0.22	0.450 (11.4)	0.190 (4.8)	0.305 (7.7)	0.394 (10)	0.025 (.6)	75	RA4	224K250RA4 __
334	0.33	0.450 (11.4)	0.250 (6.3)	0.330 (8.4)	0.394 (10)	0.025 (.6)	75	RA4	334K250RA4 __
474	0.47	0.450 (11.4)	0.210 (5.3)	0.305 (7.7)	0.394 (10)	0.025 (.6)	55	RA4	474K250RA4 __
474	0.47	0.650 (16.5)	0.230 (5.8)	0.340 (8.6)	0.591 (15)	0.032 (.8)	50	RA6	474K250RA6 __
105	1.0	0.650 (16.5)	0.240 (6.1)	0.340 (8.6)	0.591 (15)	0.032 (.8)	35	RA6	105K250RA6 __

Dimensions in inches, metric (mm) in parenthesis.

Tolerance: K (\pm 10%) standard, J (\pm 5%) available

RoHS part number information:

No suffix indicates RoHS-5 compliant standard part number. RoHS-5 product does not contain five of the RoHS banned materials (Hg, CrVI, Cd, PBB and PBDE) in levels exceeding the industry defined limits.

Component lead wires are plated with Sn / Pb and match conventional SnPb board assembly requirements.

For a RoHS-6 compliant part, add a -FA suffix. RoHS-6 product does not contain any of the six RoHS banned materials (Hg, CrVI, Cd, PBB, PBDE and Pb) in levels exceeding the industry defined limits.

Component lead wires are plated with Sn.

400 VDC / 250 VAC

PF Code	Value μF	L Max	TMax	H Max	S \pm .02 [.5]	d	Max dv/dt (V/ μs)	Case	Part No.
224	0.22	0.650 (16.5)	0.230 (5.8)	0.340 (8.6)	0.591 (15)	0.032 (.8)	65	RA6	224K400RA6__
474	0.47	0.650 (16.5)	0.290 (7.4)	0.440 (11.1)	0.591 (15)	0.032 (.8)	120	RA6	474K400RA6__

500 VDC / 250 VAC

PF Code	Value μF	L Max	TMax	H Max	S \pm .02 [.5]	d	Max dv/dt (V/ μs)	Case	Part No.
504	0.5	0.650 (16.5)	0.280 (7.1)	0.540 (13.7)	0.591 (15)	0.032 (.8)	120	RA6	504K500RA6__

Dimensions in inches, metric (mm) in parenthesis.

Tolerance: K (\pm 10%) standard, J (\pm 5%) available

RoHS part number information: _____

No suffix indicates RoHS-5 compliant standard part number. RoHS-5 product does not contain five of the RoHS banned materials (Hg, CrVI, Cd, PBB and PBDE) in levels exceeding the industry defined limits. Component lead wires are plated with Sn / Pb and match conventional SnPb board assembly requirements.

For a **RoHS-6** compliant part, add a **-FA** suffix. RoHS-6 product does not contain any of the six RoHS banned materials (Hg, CrVI, Cd, PBB, PBDE and Pb) in levels exceeding the industry defined limits. Component lead wires are plated with Sn.

Electrical	Performance	Physical						
<p>Capacitance Range: 0.1 μF to 10.0 μF @ 1KHz</p> <p>Tolerance: Available in \pm 5%, 10% (standard), 20%</p> <p>Voltage Range: 100, 250, 400, 500 VDC</p> <p>Dissipation Factor: \leq 1.0 % @ 25°C, 1KHz</p> <p>Insulation Resistance: \geq 1,000 Megohms x μF Need not exceed 1,000 Megohms</p> <table border="1"> <tr> <td>Rated Voltage</td> <td>\leq 100 VDC</td> <td>$>$ 100 VDC</td> </tr> <tr> <td>Test Voltage</td> <td>10 VDC</td> <td>100 VDC</td> </tr> </table> <p>Dielectric Strength: 1.6 x RVDC, 2 seconds max. (Bold P/Ns) 1.3 x RVDC, 2 seconds max.</p> <p>Self Inductance: 2 to 6nh typical</p> <p>Temperature Range: -55°C to 125°C @ rated DC voltage (Bold P/Ns) -55°C to 125°C, derate voltage 1.25% / °C above 85°C</p>	Rated Voltage	\leq 100 VDC	$>$ 100 VDC	Test Voltage	10 VDC	100 VDC	<p>Accelerated DC Voltage Life Test: 1,000 Hours, 85°C, 1.25 x Rated VDC Δ C/C \leq 5% DF \leq 1.0%, 1KHz, 25°C IR \geq 1,000 Megohm x μF Need not exceed 1,000 Megohms</p> <p>Moisture Test: 85°C / 85% RH / 21 days Applied Voltage: zero bias Δ C/C \leq 7% DF \leq 1.0%, 1KHz, 25°C IR \geq 30% of initial limit</p> <p>Long Term Stability: After 2 years storage, standard environment Δ C/C \leq 2%</p>	<p>Vibration: Mil Std 202 Method 204D</p> <p>Solder Resistance: 260°C, 5 Sec. Δ C/C \leq 2%</p> <p>Construction: Non-inductively constructed with metallized poly-ester dielectric (polyethylene terephthalate). Parallel plate-multilayer polymer (MLP) design.</p> <p>Electrode: Aluminum metallization</p> <p>Case: Polyester tape wrap</p> <p>Marking: Parts are continuously marked ⊕⊕ and pf code. Capacitance, tolerance and working voltage are printed on container.</p> <p>Packaging: Bulk Packaging Standard</p>
Rated Voltage	\leq 100 VDC	$>$ 100 VDC						
Test Voltage	10 VDC	100 VDC						

Angstor® Capacitor Application Notes

Paktron developed the highly advanced Interleaf® Technology method of capacitor manufacturing to improve device electrical properties and stability in actual use conditions. As opposed to the conventional winding method, Interleaf® Technology uses a high laminating pressure, linear stacking technology. The resulting capacitor chip is a construction hybrid resembling a multilayer ceramic capacitor in cross section, while offering all the fail-safe advantages of a stacked plastic film capacitor. We refer to the resultant parts as MLP or multilayer polymer. The Angstor® Capacitor (or RA Style) is a self-encased, metallized film capacitor which features small size, high dv/dt capability and very low ESR at high frequency.

Intended for thru-hole and wired applications, the units feature all aluminum electrodes and terminals that are pulse welded to the lead wires. The units are back impregnated with a microcrystalline polymer sealant, and require no external coatings for moisture protection. The internal layers are heavily laminated to eliminate air from the core material which improves high frequency response compared to competitive units. Operating temperature limit is extended to 125°C.

The following are a few examples of applications wherein the Angstor's unique features have proven desirable:

HIGH FREQUENCY SWITCHING POWER INPUTS

As the modern power converter broke the 100 KHz switching frequency barrier, the ripple voltage and RFI control components changed drastically. On the input side of 48 volt converters, a low ESR and ESL capacitor is needed in the pi filter network to control EMI generated by the switching MOSFET. Metallized film capacitors should be used because of the voltage bias and due to the unit's ability to "clear" during a high voltage event, rather than short out like a common MLC capacitor. Electrolytic (aluminum and tantalum) capacitors are not useful because of their extremely high parasitic resistance and inductance. Under ripple voltage the Angstor is stable, while ceramic capacitors increase in loss factor, creating incremental I²R losses.

LINE AND DATA LINE NOISE SUPPRESSION

A $\geq 250V$ Angstor will not lose value due to the bias voltage and can be used on higher voltage lines as a differential noise bypass for RFI control. High input dv/dt up to 100 volts per micro second can be handled. In modems, the Angstor is a space efficient alternative to other input current control devices. Since the capacitor body is "plastic" there exists no piezoelectric emf due to input di/dt.

EMI/RFI SUPPRESSION

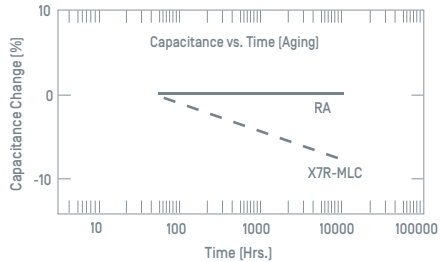
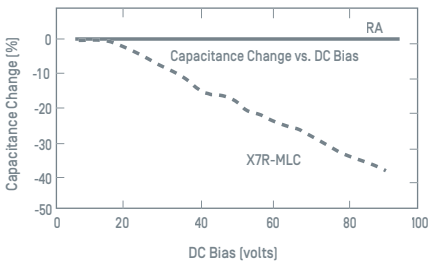
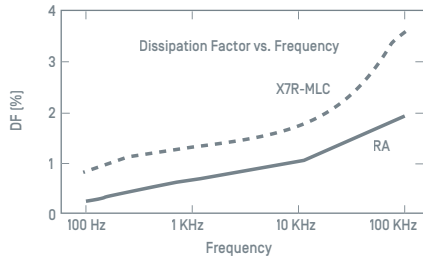
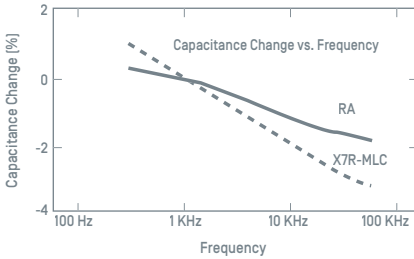
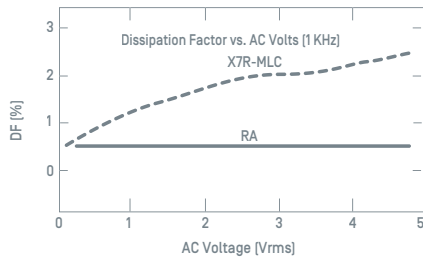
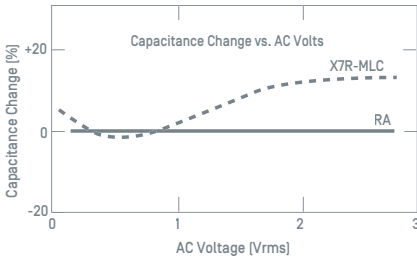
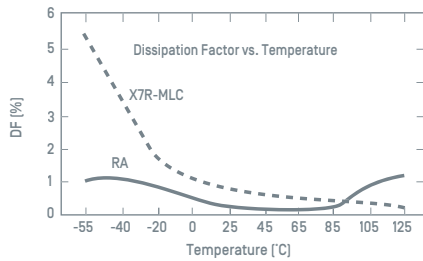
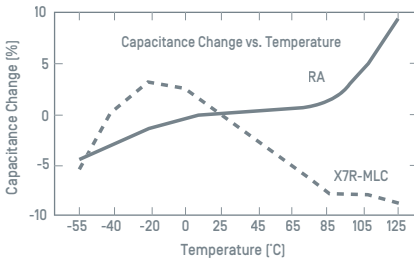
Noise suppression is required on a variety of motors and field effect devices close to the offending source to minimize RFI on the voltage bus. Noise or transients emanating from switched state motors or inductors require a low ESR capacitor as part of the filtering arrangement. The Angstor is an excellent choice for these 12, 36 and 48 volt bus-rails because of its small size compared to other film capacitors and better ESR and reliability than ceramic capacitors. As the automotive bus voltage rises from 12 to 36/42 volts, this technology will replace many ceramic and tantalum capacitors because of its enhanced voltage coefficient (stability).

A significant new market is in on-board converters to charge batteries in EV and HEV applications

GRACEFUL AGING

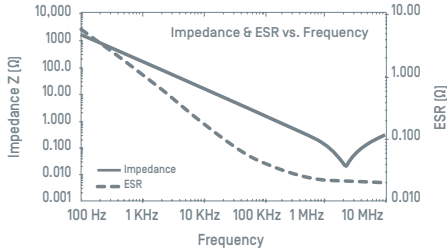
There exists no chemical interactions within the MLP Capacitor to effect long term life. The parts are suitable for 10 to 20 year life applications due to their stability and inherently low loss. The polymer dielectric becomes more crystalline over long periods of time, which can gradually lower the capacitance value. The thin-film metallized electrodes are capable of "self healing" under high voltage events. This feature avoids the shorting, cracking and rapid heat generation problem often found in ceramic capacitors.

Typical Performance Characteristics: MLP Film vs. Ceramic

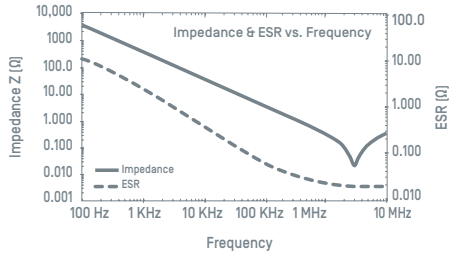


Typical Performance Curves Selected High Value "Power" Capacitors

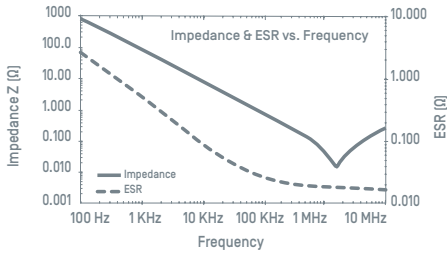
1.0 μF 100 VDC RA4



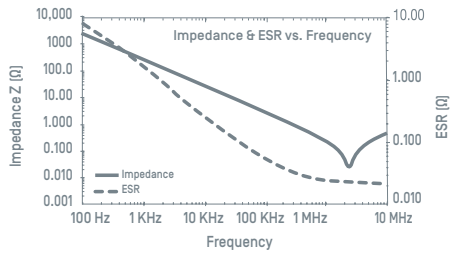
0.47 μF 250 VDC RA4



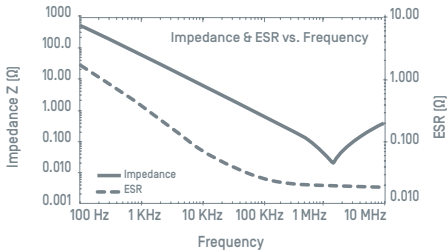
2.2 μF 100 VDC RA4



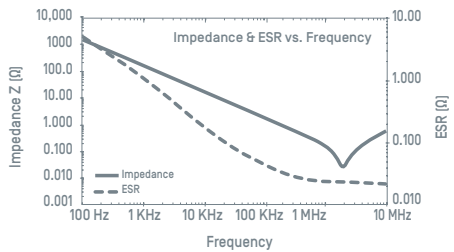
0.47 μF 400 VDC RA6



3.3 μF 100 VDC RA4

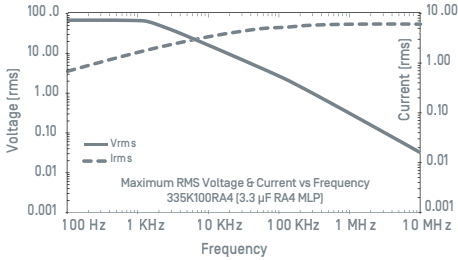


1.0 μF 250 VDC RA6

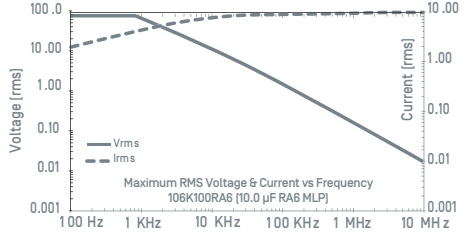


Typical Performance Curves Selected High Value "Power" Capacitors

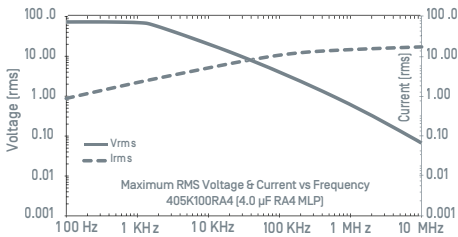
3.3 μF 100 VDC RA4



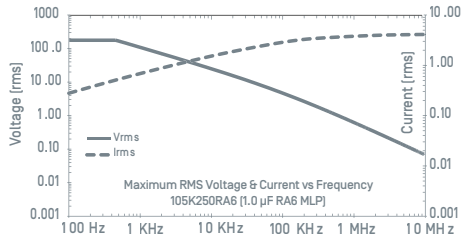
10.0 μF 100 VDC RA6



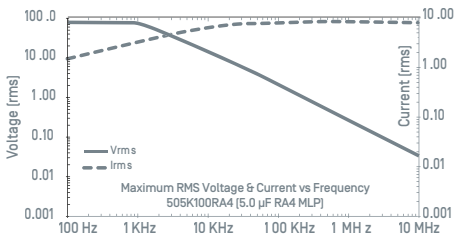
4.0 μF 100 VDC v



1.0 μF 250 VDC RA6



5.0 μF 100 VDC RA4



0.47 μF 400 VDC RA6

